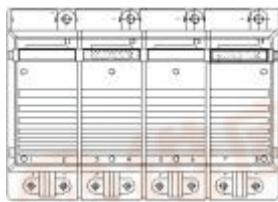


# SKIIP 642GH120-4D



**SKIIP® 2**

## 4-pack - integrated intelligent Power System

### Power section

#### SKIIP 642GH120-4D

### Features

- SKIIP technology inside
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKIIP® 2 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized file no. E63532

- 1) with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)
- 2) AC connection busbars must be connected by the user; copper busbars available on request

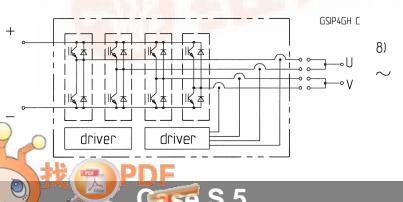
Absolute Maximum Ratings		$T_s = 25^\circ\text{C}$ unless otherwise specified		
Symbol	Conditions	Values		Units
<b>IGBT</b>				
$V_{CES}$		1200		V
$V_{CC}$ <sup>1)</sup>	Operating DC link voltage	900		V
$V_{GES}$		$\pm 20$		V
$I_C$	$T_s = 25 \text{ (70)}^\circ\text{C}$	600 (450)		A
<b>Inverse diode</b>				
$I_F = -I_C$	$T_s = 25 \text{ (70)}^\circ\text{C}$	600 (450)		A
$I_{FSM}$	$T_j = 150^\circ\text{C}$ , $t_p = 10 \text{ ms}$ ; sin.	4320		A
$I_{\text{ft}}$ (Diode)	Diode, $T_j = 150^\circ\text{C}$ , 10 ms	93		kA <sup>2</sup> s
$T_j$ ( $T_{\text{stg}}$ )		- 40 (- 25) ... + 150 (125)		°C
$V_{\text{isol}}$	AC, 1 min. (mainterminals to heat sink)	3000		V

Characteristics		$T_s = 25^\circ\text{C}$ unless otherwise specified		
Symbol	Conditions	min.	typ.	max.
<b>IGBT</b>				
$V_{CEsat}$	$I_C = 500 \text{ A}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	2,6 (3,1)	3,1	V
$V_{CEO}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	1,2 (1,3)	1,5 (1,6)	V
$r_{CE}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	2,6 (3,5)	3,2 (4)	mΩ
$I_{CES}$	$V_{GE} = 0 \text{ V}$ , $V_{CE} = V_{CES}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	(30)	0,8	mA
$E_{\text{on}} + E_{\text{off}}$	$I_C = 500 \text{ A}$ , $V_{CC} = 600 \text{ V}$ $T_j = 125^\circ\text{C}$ , $V_{CC} = 900 \text{ V}$		150	mJ
			265	mJ
$R_{CC'} + EE'$	terminal chip, $T_j = 125^\circ\text{C}$	0,25		mΩ
$L_{CE}$	top, bottom	7,5		nH
$C_{CHC}$	per phase, AC-side	2,8		nF
<b>Inverse diode</b>				
$V_F = V_{EC}$	$I_F = 500 \text{ A}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	2,1 (2)	2,6	V
$V_{TO}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	1,3 (1)	1,4 (1,1)	V
$r_T$	$T_j = 25 \text{ (125)}^\circ\text{C}$	1,7 (2)	2,3 (2,6)	mΩ
$E_{\text{rr}}$	$I_C = 500 \text{ A}$ , $V_{CC} = 600 \text{ V}$ $T_j = 125^\circ\text{C}$ , $V_{CC} = 900 \text{ V}$		19	mJ
			25	mJ
<b>Mechanical data</b>				
$M_{dc}$	DC terminals, SI Units	6	8	Nm
$M_{ac}$	AC terminals, SI Units	13	15	Nm
w	SKIIP® 2 System w/o heat sink		3,5	kg
w	heat sink		8,5	kg

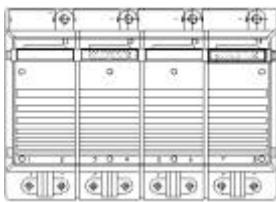
### Thermal characteristics (P16 heat sink; 275 m<sup>3</sup>/h); "r" reference to temperature sensor

$R_{\text{th(j-s)l}}$	per IGBT	tau <sub>i</sub> (s)			
		1	2	3	4
$R_{\text{th(j-s)D}}$	per diode			0,045	K/W
$R_{\text{th(s-a)}}$	per module			0,125	K/W
$R_{\text{th(s-a)}}$				0,033	K/W
$Z_{\text{th}}$	$R_i$ (mK/W) (max. values)				
	1	2	3	4	
$Z_{\text{th(j-r)l}}$	5	35	5	0	1
$Z_{\text{th(j-r)D}}$	14	96	15	0	1
$Z_{\text{th(r-a)}}$	1,6	22	7	2,4	1
				494	0,03
				165	20

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# SKiiP 642GH120-4D



SKiiP® 2

## 4-pack - integrated intelligent Power System

### 4-pack integrated gate driver

### SKiiP 642GH120-4D

### Gate driver features

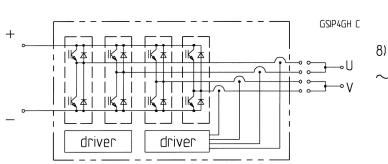
- Two separate and independent "GB"-type driver
- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- U-option is integrated on left driver, (DC terminals at bottom; refer to case drawing)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option)
- IEC 60068-1 (climate) 25/85/56

Absolute Maximum Ratings		$T_a = 25^\circ\text{C}$ unless otherwise specified	
Symbol	Conditions	Values	Units
$V_{S1}$	stabilized 15 V power supply	18	V
$V_{S2}$	unstabilized 24 V power supply	30	V
$V_{IH}$	input signal voltage (high)	15 + 0,3	V
$dv/dt$	secondary to primary side	75	kV/μs
$V_{isolIO}$	input / output (AC, r.m.s., 2s)	3000	Vac
$V_{isol12}$	output 1 / output 2 (AC, r.m.s., 2s)	1500	Vac
$f_{sw}$	switching frequency	20	kHz
$f_{out}$	output frequency for $I=I_C \cdot \sin.$	1	kHz
$T_{op} (T_{stg})$	operating / storage temperature	- 40 ... + 85	°C

Characteristics ( $T_a = 25^\circ\text{C}$ )				
Symbol	Conditions	min.	typ.	max.
$V_{S1}$	supply voltage stabilized	14,4	15	15,6
$V_{S2}$	supply voltage non stabilized	20	24	30
$I_{S1}$	$V_{S1} = 15\text{ V}$	$210+430*f/f_{max}+1,2*(I_{AC}/A)$		
$I_{S2}$	$V_{S2} = 24\text{ V}$	$160+290*f/f_{max}+0,85*(I_{AC}/A)$		
$V_{IT+}$	input threshold voltage (High)	12,3		
$V_{IT-}$	input threshold voltage (Low)	4,6		
$R_{IN}$	input resistance	10		
$t_{d(on))IO}$	input-output turn-on propagation time	1,5		
$t_{d(off))IO}$	input-output turn-off propagation time	1,4		
$t_{pERRRESET}$	error memory reset time	9		
$t_{TD}$	top / bottom switch : interlock time	3,3		
$I_{analogOUT}$	8 V corresponds to max. current of 15 V supply voltage (available when supplied with 24 V)	600		
$I_{Vs1outmax}$	output current at pin 12/14	50		
$I_{A0max}$	logic low output voltage	5		
$V_{O1}$	logic high output voltage	0,6		
$V_{OH}$		30		
$I_{TRIPSC}$	over current trip level ( $I_{analog OUT} = 10\text{ V}$ )	750		
$I_{TRIPLG}$	ground fault protection	110		
$T_{tp}$	over temperature protection	120		
$U_{DCTRIP}$	trip level of $U_{DC}$ -protection ( $U_{analog OUT} = 9\text{ V}$ ); (option)	900		

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Case S 5